

PCTEST ENGINEERING LABORATORY, INC.

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HEARING AID COMPATIBILITY

Applicant Name:

Samsung Electronics Co., Ltd. 129, Samsung-ro, Maetan dong, Yeongtong-gu, Suwon-si Gyeonggi-do 16677, Korea Date of Testing: 11/13/2017 - 11/15/2017 Test Site/Location: PCTEST Lab, Columbia, MD, USA Test Report Serial No.: 1M1711130296-03.A3L

FCC ID:

A3LSMA730F

APPLICANT:

SAMSUNG ELECTRONICS CO., LTD.

Scope of Test: Application Type: FCC Rule Part(s): HAC Standard:

DUT Type: Model: Additional Model(s): Test Device Serial No.: Original Grant Date: Class II Permissive Change(s): RF Emissions Testing Class II Permissive Change CFR §20.19(b) ANSI C63.19-2011 285076 D01 HAC Guidance v05 Portable Handset SM-A730F/DS SM-A730F *Pre-Production Sample* [S/N: 12531] 11/09/2017 See FCC Change Document

C63.19-2011 HAC Category:

M4 (RF EMISSIONS CATEGORY)

This wireless portable device has been shown to be hearing-aid compatible under the above rated category, specified in ANSI/IEEE Std. C63.19-2011 and has been tested in accordance with the specified measurement procedures. Hearing-Aid Compatibility is based on the assumption that all production units will be designed electrically identical to the device tested in this report. Test results reported herein relate only to the item(s) tested. North America bands only.

I attest to the accuracy of data. All measurements reported herein were performed by me or were made under my supervision and are correct to the best of my knowledge and belief. I assume full responsibility for the completeness of these measurements and vouch for the qualifications of all persons taking them.

Randy Ortanez President



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1. INTRODUCTION

On July 10, 2003, the Federal Communications Commission (FCC) adopted new rules requiring wireless manufacturers and service providers to provide digital wireless phones that are compatible with hearing aids. The FCC has modified the exemption for wireless phones under the Hearing Aid Compatibility Act of 1998 (HAC Act) in WT Docket 01-309 RM-8658¹ to extend the benefits of wireless telecommunications to individuals with hearing disabilities. These benefits encompass business, social and emergency communications, which increase the value of the wireless network for everyone. An estimated more than 10% of the population in the United States show signs of hearing impairment and of that fraction, almost 80% use hearing aids. Approximately 500 million people worldwide suffer from hearing loss.

Compatibility Tests Involved:

The standard calls for wireless communications devices to be measured for:

- RF Electric-field emissions
- T-coil mode, magnetic-signal strength in the audio band
- T-coil mode, magnetic-signal frequency response through the audio band
- T-coil mode, magnetic-signal and noise articulation index

The hearing aid must be measured for:

- RF immunity in microphone mode
- RF immunity in T-coil mode

In the following tests and results, this report includes the evaluation for a wireless communications device.



Figure 1-1 Hearing Aid *in-vitu*

¹ FCC Rule & Order, WT Docket 01-309 RM-8658

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DUT DESCRIPTION 2.



FCC ID:	A3LSMA730F
Manufacturer:	Samsung Electronics Co., Ltd.
	129, Samsung-ro, Maetan dong,
	Yeongtong-gu, Suwon-si
	Gyeonggi-do 16677, Korea
Model:	SM-A730F/DS
Additional Model(s):	SM-A730F
Serial Number:	12531
Antenna Configurations:	Internal Antenna
HAC Test Configurations:	GSM 850, 128, 190, 251, BT Off, WLAN Off, LTE Off
DUT Type:	Portable Handset

Table 2-1: A3LSMA730F HAC Air Interfaces

Air-Interface	Band (MHz)	Type Transport	HAC Tested	Simultaneous But Not Tested	Voice over Digital Transport OTT Capability	Additional GSM Power Reduction
	850	1/0	Yes		N1/A	Ne
GSM	1900	VO	No ¹	Yes: WIFI or BT	N/A	No
	GPRS/EDGE	DT	No	Yes: WIFI or BT	Yes	No
	850					
UMTS	1700	VD	No ¹	Yes: WIFI or BT	N/A	N/A
UIVITS	1900					
	HSPA	DT	No	Yes: WIFI or BT	Yes	N/A
	700 (B12)					N/A
	700 (B17)			No ¹ Yes: WIFI or BT	Yes	
	780 (B13)					
LTE (FDD)	850 (B5)	VD	No ¹			
	850 (B26)	VD	NO	res. will of bi		
	1700 (B4)					
	1700 (B66)					
	1900 (B2)					
LTE (TDD)	2600 (B41)	VD	No ¹	Yes: WIFI or BT	Yes	N/A
	2450					
	5200					
WIFI	5300	VD	No ¹	Yes: GSM, UMTS, or LTE	Yes N/A	N/A
	5500					
	5800					
BT	2450	DT	No	Yes: GSM, UMTS, or LTE	N/A	N/A
Type Transport VO = Voice Onl			Notes: 1. This report	only pertains to GSM 850 voice m	node. Please refer to the o	riginal certification

DT = Digital Data - Not intended for CMRS Service technical evaluation (Test Report SN: 1M1710050266-11-R1.A3L) for full test data.

VD = CMRS and Data Transport

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ANSI/IEEE C63.19 PERFORMANCE CATEGORIES 3.

I. RF EMISSIONS

The ANSI Standard presents performance requirements for acceptable interoperability of hearing aids with wireless communications devices. When these parameters are met, a hearing aid operates acceptably in close proximity to a wireless communications device.

Category	Telephone RF Parameters			
Near field Category	E-field emissions CW dB(V/m)			
	f < 960 MHz			
M1	50 to 55			
M2	45 to 50			
M3	40 to 45			
M4	< 40			
	f > 960 MHz			
M1	40 to 45			
M2	35 to 40			
M3	30 to 35			
M4	< 30			
Table 3-1 WD near-field categories as defined in ANSI C63.19-2011				

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SYSTEM SPECIFICATIONS 4.

ER3DV6 E-Field Probe Description

Construction:	One dipole parallel, two dipoles normal to probe axis
Calibration:	Built-in shielding against static charges In air from 100 MHz to 3.0 GHz (absolute accuracy ±6.0%, k=2)
Frequency:	100 MHz to > 6 GHz;
	Linearity: ± 0.2 dB (100 MHz to 3 GHz)
Directivity	± 0.2 dB in air (rotation around probe axis)
	± 0.4 dB in air (rotation normal to probe axis)
Dynamic Range	2 V/m to > 1000 V/m
, ,	(M3 or better device readings fall well below diode
	compression point)
Linearity:	± 0.2 dB
Dimensions	Overall length: 330 mm (Tip: 16 mm)
	Tip diameter: 8 mm (Body: 12 mm)
	Distance from probe tip to dipole centers: 2.5 mm

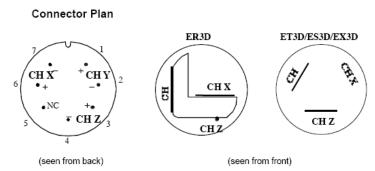


Figure 4-1 E-field Free-space Probe

Probe Tip Description

HAC field measurements take place in the close near field with high gradients. Increasing the measuring distance from the source will generally decrease the measured field values (in case of the validation dipole approx. 10% per mm).

The electric field probes have an irregular internal geometry because it is physically not possible to have the 3 orthogonal sensors situated with the same center. The effect of the different sensor centers is accounted for in the HAC uncertainty budget ("sensor displacement"). Their geometric center is at 2.5mm from the tip, and the element ends are 1.1mm closer to the tip.



The antistatic shielding inside the probe is connected to the probe connector case.

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Instrumentation Chain

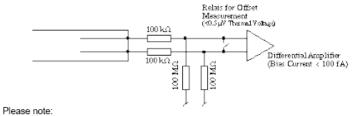
Equation 1 Conversion of Connector Voltage u_i to E-Field E_i

$$E_i = \sqrt{\frac{u_i + (u_i^2 \cdot CF)/(DCP)}{Norm_i \cdot ConvF}}$$

whereby

Ei:	electric field in V/m
Uj.	voltage of channel i at the connector in μV
Norm	sensitivity of channel i in µV/(V/m) ²
ConvF:	enhancement factor in liquid (ConvF=1 for Air)
DCP:	diode compression point in µV
CF:	signal crest factor (peak power/average power)

Conditions of Calibration



a lower input impedance of the amplifier will result in different sensitivity factors Norm, and DCP

larger bias currents will cause higher offset

Probe Response to Frequency

The E-field sensors have inherently a very flat frequency response. They are calibrated with a number of frequencies resulting in a common calibration factor, with the frequency behavior documented in the calibration certificate (See also below).

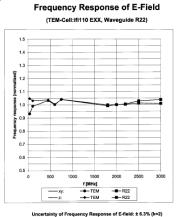


Figure 4-2 E-Field Probe Frequency Response

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SPEAG Robotic System

E-field measurements are performed using the DASY5 automated dosimetric assessment system. The DASY5 is made by Schmid & Partner Engineering AG (SPEAG) in Zurich, Switzerland and consists of high precision robotics system (Staubli), robot controller, Intel CORE i7 computer, nearfield probe, probe alignment sensor, and the HAC phantom. The robot is a six-axis industrial robot performing precise movements to position the probe to the location (points) of maximum electromagnetic field (EMF).



Figure 4-3 SPEAG Robotic System

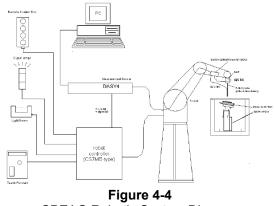
System Hardware

A cell controller system contains the power supply, robot controller, teach pendant (Joystick), and a remote control used to drive the robot motors. The PC consists of the computer with operating system and RF Measurement Software DASY5 v52.8 (with HAC Extension), A/D interface card, monitor, mouse, and keyboard. The Staubli Robot is connected to the cell controller to allow software manipulation of the robot. A data acquisition electronic (DAE) circuit that performs the signal amplification, signal multiplexing, AD-conversion, offset measurements, mechanical surface detection, collision detection, etc. is connected to the Electro-optical coupler (EOC). The EOC performs the conversion from the optical into digital electric signal of the DAE and transfers data to the PC plug-in card.

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System Electronics

The DAE consists of a highly sensitive electrometer-grade preamplifier with auto-zeroing, a channel and gain-switching multiplexer, a fast 16 bit AD-converter and a command decoder and control logic unit. Transmission to the PC-card is accomplished through an optical downlink for data and status information and an optical uplink for commands and clock lines. The mechanical probe mounting device includes two different sensor systems for frontal and sidewise probe contacts. They are also used for mechanical surface detection and probe collision detection. The robot uses its own controller with a built in VME-bus computer.



SPEAG Robotic System Diagram

DASY5 Instrumentation Chain

The first step of the evaluation is a linearization of the filtered input signal to account for the compression characteristics of the detector diode. The compensation depends on the input signal, the diode type and the DC-transmission factor from the diode to the evaluation electronics. If the exciting field is pulsed, the crest factor of the signal must be known to correctly compensate for peak power. The formula for each channel can be given as:

$$V_i = U_i + U_i^2 \cdot \frac{cf}{dcp_i}$$

with	V_i	= compensated signal of channel i	(i = x, y, z)
	U_i	= input signal of channel i	(i = x, y, z)
	cf	= crest factor of exciting field	(DASY parameter)
	dcp_i	= diode compression point	(DASY parameter)

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From the compensated input signals the primary field data for each channel can be evaluated:

ConvF = sensitivity enhancement in solution

 E_i = electric field strength of channel i in V/m

The RSS value of the field components gives the total field strength (Hermitian magnitude):

$$E_{tot} = \sqrt{E_x^2 + E_y^2 + E_z^2}$$

z)

z)

The primary field data are used to calculate the derived field units.

The measurement/integration time per point, as specified by the system manufacturer is >500ms.

The signal response time is evaluated as the time required by the system to reach 90% of the expected final value after an on/off switch of the power source with an integration time of 500ms and a probe response time of <5 ms. In the current implementation, DASY5 waits longer than 100ms after having reached the grid point before starting a measurement, i.e., the response time uncertainty is negligible.

If the device under test does not emit a CW signal, the integration time applied to measure the electric field at a specific point may introduce additional uncertainties due to the discretization. The tolerances for the different systems had the worst-case of 2.6%.

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5. TEST PROCEDURE

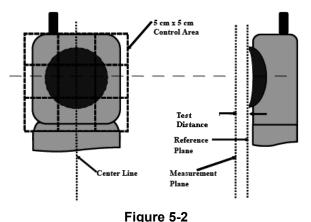
I. RF EMISSIONS

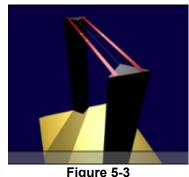
Test Instructions Confirm proper operation of ≻ probes and instrumentation Position WD \geq **Configure WD TX operation** ≻ Per 5.5.1.2 (a-c) Initialize field probe \triangleright ≻ Scan Area Per 5.5.1.2 (d-f) Identify exclusion area. \geq \geq Rescan or reanalyze open area to determine maximum Indirect method: Add the MIF ≻ to the maximum steady state rms field strength and record **RF** Audio Interference Level, in dB(V/m) Per 5.5.1.2 (g-h) & 5.5.1.3 Identify and record the ≻ category Per 5.5.1.2 (i-j)

Figure 5-1 RF Emissions Flow Chart

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Test Setup





HAC Phantom

E-Field Emissions Test Setup Diagram (See Test Photographs for actual WD scan grid overlay)

RF Emissions Test Procedure:

The following illustrate a typical RF emissions test scan over a wireless communications device:

- 1. Proper operation of the field probe, probe measurement system, other instrumentation, and the positioning system was confirmed.
- 2. WD is positioned in its intended test position, acoustic output point of the device perpendicular to the field probe.
- 3. The WD operation for maximum rated RF output power was configured and confirmed with the base station simulator, at the test channel and other normal operating parameters as intended for the test. The battery was ensured to be fully charged before each test.
- 4. The center sub-grid was centered over the center of the acoustic output (also audio band magnetic output, if applicable). The WD audio output was positioned tangent (as physically possible) to the measurement plane.
- 5. A surface calibration was performed before each setup change to ensure repeatable spacing and proper maintenance of the measurement plane using the HAC Phantom.
- 6. The measurement system measured the field strength at the reference location.
- 7. Measurements at 2mm or 5mm increments in the 5 x 5 cm region were performed at a distance 15 mm from the center point of the probe measurement element to the WD. A 360° rotation about the azimuth axis at the maximum interpolated position was measured. For the worst-case condition, the peak reading from this rotation was used in re-evaluating the HAC category.
- 8. The system performed a drift evaluation by measuring the field at the reference location. If the power drift deviated by more than 5%, the HAC test and drift measurements were repeated.

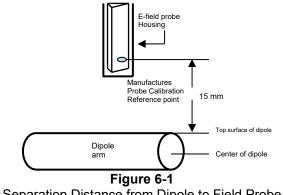
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6. SYSTEM CHECK

I. System Check Parameters

The input signal was an un-modulated continuous wave. The following points were taken into consideration in performing this check:

- Average Input Power P = 100mW RMS (20dBm RMS) after adjustment for return loss
- The test fixture must meet the 2 wavelength separation criterion
- The proper measurement of the 15 mm probe to dipole separation, which is measured from top surface of the dipole to the calibration reference point of the sensor, defined by the probe manufacturer is shown in the following diagram:



Separation Distance from Dipole to Field Probe

RF power was recorded using both an average reading meter and a peak reading meter. Readings of the probe are provided by the measurement system.

To assure proper operation of the near-field measurement probe the input power to the dipole shall be commensurate with the full rated output power of the wireless device [e.g. - for a cellular phone wireless device the average peak antenna input power will be on the order of 100mW (20dBm) RMS] after adjustment for any mismatch.

II. Validation Procedure

A dipole antenna meeting the requirements given in C63.19 was placed in the position normally occupied by the WD.

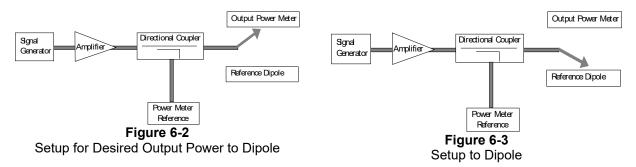
The length of the dipole was scanned, and the average peak value was recorded.

Measurement of CW

Using the near-field measurement system, scan the antenna over the radiating dipole and record the greatest field reading observed. Due to the nature of E-fields about free-space dipoles, the two E-field peaks measured over the dipole are averaged to compensate for non-parallelity of the setup (see manufacturer method on dipole calibration certificates, page 2). Field strength measurements shall be made only when the probe is stationary.

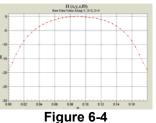
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RF power was recorded using both an average and a peak power reading meter.

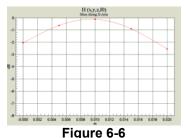


Using this setup configuration, the signal generator was adjusted for the desired output power (100mW) at a specified frequency. The reference power from the coupled port of the directional coupler is recorded. Next, the output cable is connected to the reference dipole, as shown in Figure 6-3.

The input signal level was adjusted until the reference power from the coupled port of the directional coupler was the same as previously recorded, to compensate for the impedance mismatch between the output cable and the reference dipole. To assure proper operation of the near-field measurement probe the input power to the reference dipole was verified to the full rated output power of the wireless device. The dipole was secured in a holder in a manner to meet the 20 dB reflection. The near-field measurement probe was positioned over the dipole. The antenna was scanned over the appropriate sized area to cover the dipole from end to end. SPEAG uses 2D interpolation algorithms between the measured points. Please see below two dimensional plots showing that the interpolated values interpolate smoothly between 5mm steps for a free-space RF dipole:



2-D Raw Data from scan along dipole axis



2-D Raw Data from scan along transverse axis



2-D Interpolated points from scan along dipole axis



2-D Interpolated points from scan along transverse axis

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III. System Check Results

Validation Results

Date	Frequency (MHz)	Probe S/N	DAE S/N	Dipole S/N	Input Power (dBm)	E-field Result (V/m)	Target Field (V/m)	% Deviation
11/13/2017	835	2353	859	1082	20.0	108.1	106.8	1.2%

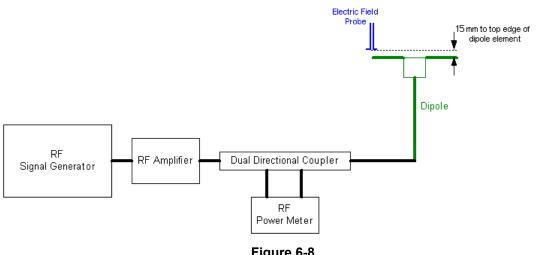


Figure 6-8 System Check Setup

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7. MODULATION INTERFERENCE FACTOR

I. Measuring Modulation Interference Factors

For any specific fixed and repeatable modulated signal, a modulation interference factor (MIF, expressed in dB) may be determined that relates its interference potential to its steady-state RMS signal level or average power level. This factor is a function only of the audio-frequency amplitude modulation characteristics of the signal and is the same for field-strength and conducted power measurements. The MIF is valid only for a specific repeatable audio-frequency amplitude modulation characteristic; any change in modulation characteristic requires determination and application of a new MIF.

The MIF may be determined using a radiated RF field or a conducted RF signal:

- a. Using RF illumination or conducted coupling, apply the specific modulated signal in question to the measurement system at a level within its confirmed operating dynamic range.
- b. Measure the steady-state RMS level at the output of the fast probe or sensor.
- c. Measure the steady-state average level at the weighting output.
- d. Without changing the square-law detector or weighting system, and using RF illumination or conducted coupling, substitute for the specific modulated signal a 1 kHz, 80% amplitude modulated carrier at the same frequency and adjust its strength until the level at the weighting output equals the step c) measurement.
- e. Without changing the carrier level from step d), remove the 1 kHz modulation and again measure the steady-state RMS level indicated at the output of the fast probe or sensor.
- f. The MIF for the specific modulation characteristic is provided by the ratio of the step e) measurement to the step b) measurement, expressed in dB (20 × log[(step e)/(step b)]).

The following procedure was used to measure the MIF using the SPEAG Audio Interference Analyzer (AIA), Type No: SE UMS 170 CB, Serial No.: 1010:

- 1. The device was placed into a simulated call using a base station simulator or set to transmit using test software for a given mode.
- 2. The device was then set to continuously transmit at maximum power.
- 3. Using a coupler if needed, the device output signal was connected to the RF In port of the AIA, which was connected to a desktop computer. Alternatively, a radiated RF signal may be used with the AIA's built-in antenna.
- 4. The MIF measurement procedure in the DASY software was run, and the resulting MIF value was recorded.
- 5. Steps 1-4 were repeated for all CMRS air interfaces, frequency bands, and modulations.

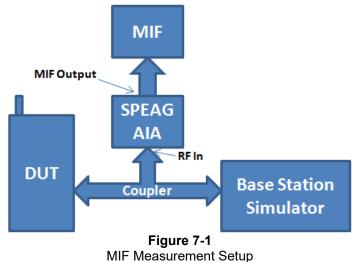
The modulation interference factors obtained were applied to readings taken of the actual wireless device in order to obtain an accurate audio interference level reading using the formula:

Audio Interference Level [dB(V/m)] = 20 * log[Raw Field Value (V/m)] + MIF (dB)

Because the MIF value is output power independent, MIF values for a given mode should be constant across all devices; however, per C63.19-2011 §D.7, MIF values should be measured for each device being evaluated. The voice modes for this device have been investigated in this section of the report.

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II. MIF Measurement Block Diagrams



for licensed modes

III. Measured Modulation Interference Factors:

Table 7-1 GSM Modulation Interference Factors ¹						
Mode	GSM850					
wode	128	190	251			
GSM	3.52	3.52	3.52			

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8. RF CONDUCTED POWER MEASUREMENTS

I. Procedures Used to Establish RF Signal for HAC Testing

The handset was placed into a simulated call using a base station simulator in a shielded chamber. Such test signals offer a consistent means for testing HAC and are recommended for evaluating HAC. Measurements were taken with a fully charged battery. In order to verify that the device was tested and maintained at full power, this was configured with the base station simulator.

II. HAC Measurement Conditions

Output Power Verification

Maximum output power is verified on the High, Middle and Low channels for all applicable air interfaces. See Table 8-1 for air interface specific settings of transmit power parameters.

Table 8-1							
Power Control Parameters and Settings by Air Interface							
Air Interface: Parameter Name: Parameter Set To:							
GSM PCI GSM850: "5"							

III. Setup Used to Measure RF Conducted Powers

Power measurements for licensed modes were performed using a base station simulator under digital average power.



Figure 8-1 Power Measurement Setup for licensed modes

IV. GSM Conducted Powers

Band	Channel	GSM [dBm] CS (1 Slot)	
	128	33.03	
GSM 850	190	33.35	
	251	33.31	

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9. JUSTIFICATION OF HELD TO EAR MODES TESTED

I. Analysis of RF Air Interface Technologies

- **a.** According to the April 2013 TCB workshop slides, OTT data services are outside the current definition of a managed CMRS service and are currently not required to be evaluated.
- b. An analysis was performed, following the guidance of §4.3 and §4.4 of the ANSI standard, of the RF air interface technologies being evaluated. The factors that will affect the RF interference potential were evaluated, and the worst case operating modes were identified and used in the evaluation. A WD's interference potential is a function both of the WD's average near-field field strength and of the signal's audio-frequency amplitude modulation characteristics. Per §4.4, RF air interface technologies that have low power have been found to produce sufficiently low RF interference potential, so it is possible to exempt them from the product testing specified in Clause 5 of the ANSI standard. An RF air interface technology of a device is exempt from testing when its average antenna input power plus its MIF is ≤17dBm for all of its operating modes. RF air interface technologies exempted from testing in this manner are automatically assigned an M4 rating to be used in determining the overall rating for the WD.

The worst case MIF plus the worst case average antenna input power for all modes are investigated below to determine the testing requirements for this device.

Max Power + MIF calculations for Low Power Exemptions								
Air Interface	Maximum Average Power (dBm)	Worst Case MIF (dB)	Total (Power + MIF, dB)	C63.19 Testing Required				
GSM850	24.32*	3.52	27.84	Yes				

Table 9-1

II. Individual Mode Evaluations

* Note: ANSI C63.19-2011 Sec. 4.4 Footnote 20 indicates the use of a long averaging time for measuring the antenna input power when using this method of exclusion. Therefore, the frame averaged power was calculated for these modes in this investigation.

III. Low-Power Exemption Conclusions

Per ANSI C63.19-2011, RF Emissions testing for this device is required only for GSM 850 voice mode.

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10. OVERALL MEASUREMENT SUMMARY

FCC ID:	A3LSMA730F
S/N:	12531

I. E-FIELD EMISSIONS:

	HAC Data Summary for GSM E-field										
Mode	Channel	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emissi	ons										
	128	Acoustic	33.03	36.66	31.28	3.52	34.80	45.00	-10.20	M4	none
GSM850	190	Acoustic	33.35	36.40	31.22	3.52	34.74	45.00	-10.26	M4	none
	251	Acoustic	33.31	34.75	30.82	3.52	34.34	45.00	-10.66	M4	none

Table 10-1 HAC Data Summary for GSM E-field



Figure 10-1 Sample E-field Scan Overlay (See Test Setup Photographs for actual WD overlay)

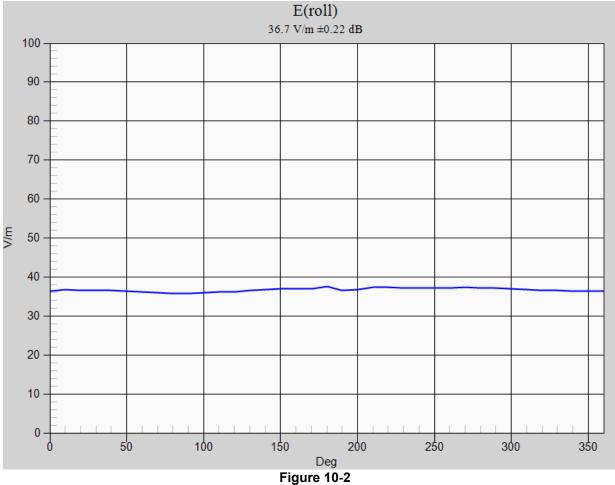
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S/N:	12531

II. Worst-case Configuration Evaluation

Peak Reading 360° Probe Rotation at Azimuth axis										
Mode	Channel	Scan Center	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
Probe Rotation	Probe Rotation at Worst-Case									
GSM850	128	Acoustic	37.50	31.48	3.52	35.00	45.00	-10.00	M4	none

Table 10-2



Worst-Case Probe Rotation about Azimuth axis

* Note: Locations of probe rotation (with and without exclusions) are shown in Figure 10-1 denoted by the green square markers.

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11. EQUIPMENT LIST

Equipment List Manufacturer Description Cal Date Cal Interval Cal Due Serial Number Model 2/28/2017 2/28/2018 MY47420800 Agilent N5182A MXG Vector Signal Generator Annual Amplifier Research 15S1G6 N/A CBT* N/A 433978 Amplifier Anritsu ML2496A Power Meter 4/20/2017 Annual 4/20/2018 1306009 Anritsu MA24106A **USB** Power Sensor 6/7/2017 Annual 6/7/2018 1244512 Anritsu MA24106A **USB** Power Sensor 6/7/2017 Annual 6/7/2018 1248508 Mini-Circuits NLP-1200+ Low Pass Filter DC to 1000 MHz N/A CBT* N/A N/A N/A CBT* N/A Mini-Circuits BW-N20W5 Power Attenuator 1226 Pasternack PE2237-20 **Bidirectional Coupler** N/A CBT* N/A N/A Rohde & Schwarz CMU200 **Base Station Simulator** N/A N/A N/A 107826 NC-100 Torque Wrench (8" lb) 9/1/2016 Biennial 9/1/2018 21053 Seekonk SPEAG Audio Interference Analzyer CBT* 1010 AIA N/A N/A SPEAG DAE4 **Dasy Data Acquisition Electronics** 5/17/2017 Annual 5/17/2018 859 SPEAG CD835V3 Freespace 835 MHz Dipole 5/10/2016 Biennial 5/10/2018 1082 SPEAG ER3DV6 Freespace E-field Probe 1/16/2017 1/16/2018 Annual 2353

Table 11-1

Calibration traceable to the National Institute of Standards and Technology (NIST).

*Note: CBT (Calibrated Before Testing). Prior to testing, the measurement paths containing a cable, attenuator, coupler or filter were connected to a calibrated source (i.e. a signal generator) to determine the losses of the measurement path. The power meter offset was then adjusted to compensate for the measurement system losses. This level offset is stored within the power meter before measurements are made. This calibration verification procedure applies to the system verification and output power measurements. The calibrated reading is then taken directly from the power meter after compensation of the losses for all final power measurements.

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12. MEASUREMENT UNCERTAINTY

Table 12-1

Uncertainty Estimation Table

Wireless Communications Device Near-Field Measurement Uncertainty Estimation							
Uncertainty Component	Data (dB)	Data Type	Prob. Dist.	Divisor	Ci (E)	Unc. (dB)	Notes/Comments
Measurement System							
RF System Reflections	0.50	Tolerance	Ν	1.00	1	0.50	* Refl. < -20 dB
Field Probe Calibration	0.21	Tolerance	Ν	1.00	1	0.21	
Field Probe Isotropy	0.01	Tolerance	Ν	1.00	1	0.01	
Field Probe Frequency Response	0.135	Tolerance	Ν	1.00	1	0.14	
Field Probe Linearity	0.013	Tolerance	Ν	1.00	1	0.01	
Modulation Interference Factor	0.20	Tolerance	R	1.73	1	0.12	Applicable for M-rating testing
Boundary Effects	0.105	Accuracy	R	1.73	1	0.06	*
Probe Positioning Accuracy	0.20	Accuracy	R	1.73	1	0.12	*
Probe Positioner	0.050	Accuracy	R	1.73	1	0.03	*
Extrapolation/Interpolation	0.045	Tolerance	R	1.73	1	0.03	*
Resolution to 2mm error	0.21	Tolerance	Ν	1.00	1	0.21	
System Detection Limit	0.05	Tolerance	R	1.73	1	0.03	*
Readout Electronics	0.015	Tolerance	Ν	1.00	1	0.02	*
Integration Time	0.11	Tolerance	R	1.73	1	0.06	*
Response Time	0.033	Tolerance	R	1.73	1	0.02	*
Phantom Thickness	0.10	Tolerance	R	1.73	1	0.06	*
System Repeatability (Field x 2=power)	0.17	Tolerance	Ν	1.00	1	0.17	*
Test Sample Related							•
Device Positioning Vertical	0.2	Tolerance	R	1.73	1	0.12	*
Device Positioning Lateral	0.045	Tolerance	R	1.73	1	0.03	*
Device Holder and Phantom	0.1	Tolerance	R	1.73	1	0.06	*
Power Drift	0.21	Tolerance	R	1.73	1	0.12	
Combined Standard Uncertainty (k=1)						0.66	16.3%
Expanded Uncertainty [95% confidence]						1.31	32.6%
Expanded Uncertainty [95% confidence]	on Field					0.66	16.3%

Notes:

1. Test equipments are calibrated according to techniques outlined in NIS81, NIS3003 and NIST Tech Note 1297. All equipments have traceability according to NIST. Measurement Uncertainties are defined in further detail in NIS 81 and NIST Tech Note 1297 and UKAS M3003.

2. * Uncertainty specifications from Schmidt & Partner Engineering AG (not site specific)

Measurement uncertainty reflects the quality and accuracy of a measured result as compared to the true value. Such statements are generally required when stating results of measurements so that it is clear to the intended audience that the results may differ when reproduced by different facilities. Measurement results vary due to the measurement uncertainty of the instrumentation, measurement technique, and test engineer. Most uncertainties are calculated using the tolerances of the instrumentation used in the measurement, the measurement setup variability, and the technique used in performing the test. While not generally included, the variability of the equipment under test also figures into the overall measurements (so-called Type A uncertainty). This may mean that the Hearing Aid immunity tests may have to be repeated by taking down the test setup and resetting it up so that there are a statistically significant number of repeat measurements to identify the measurement uncertainty. By combining the repeat measurements to identify the measurement uncertainty. By combining the repeat measurements to identify the measurement uncertainty. By and NIS 3003, the overall measurement uncertainty was estimated.

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13. TEST DATA

See following Attached Pages for Test Data.

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PCTEST Hearing-Aid Compatibility Facility

DUT: CD835V3 - SN1082

Type: CD835V3 Serial: 1082

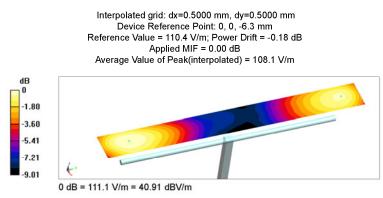
Communication System: CW; Frequency: 835 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: ER3DV6 SN2353; Calibrated: 1/16/2017;
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/17/2017
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

835 MHz / 100mW HAC Dipole Validation at 15mm/Hearing Aid Compatibility Test (41x361x1):



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Date: 11/15/2017



PCTEST Hearing-Aid Compatibility Facility

DUT: A3LSMA730F

Type: Portable Handset Serial: 12531 Backlight off Duty Cycle: 1:8.3

Communication System: GSM; Frequency: 824.2 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

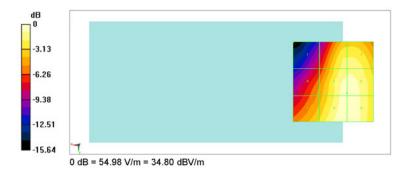
- Probe: ER3DV6 SN2353; Calibrated: 1/16/2017;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/17/2017
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

GSM850 Low Channel /Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 36.58 V/m; Power Drift = 0.18 dB Applied MIF = 3.52 dB RF audio interference level = 34.80 dBV/m Emission category: M4

MIF scaled E-field

Grid 1 M4	Grid 2 M4	Grid 3 M4
27.6 dBV/m	33.4 dBV/m	33.49 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
30.16 dBV/m	34.32 dBV/m	34.36 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
31.97 dBV/m	34.8 dBV/m	34.76 dBV/m



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14. CALIBRATION CERTIFICATES

The following pages include the probe calibration used to evaluate HAC for the DUT.

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Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland



 S
 Schweizerischer Kalibrierdienst

 C
 Service suisse d'étalonnage

 S
 Servizio svizzero di taratura

 Swiss Callbration Service

Accreditation No.: SCS 0108

Accredited by the Swiss Accreditation Service (SAS) The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

Client PC Test

Certificate No: ER3-2353_Jan17

Object	ER3DV6 - SN:2353		1
Calibration procedure(s)	QA CAL-02.v8, QA Calibration procedu evaluations in air	CAL-25.v6 Ire for E-field probes optimized for	or close near field
Calibration date:	January 16, 2017		
The measurements and the unc	ertainties with confidence prob ucled in the closed laboratory fi	Il standards, which realize the physical units ability are given on the following pages and a acility: environment temperature (22 ± 3)°C a	are part of the certificate. $2/2/$
Drimon, Chandarda	ID	Cal Date (Certificate No.)	Scheduled Calibration
Primary Standards	SN: 104778	06-Apr-16 (No. 217-02288/02289)	Apr-17
Power sensor NRP-Z91	SN: 103244	06-Apr-16 (No. 217-02288)	Apr-17
Power sensor NRP-Z91	SN: 103245	06-Apr-16 (No. 217-02289)	Apr-17
Reference 20 dB Attenuator	SN: S5277 (20x)	05-Apr-16 (No. 217-02293)	Apr-17
Reference Probe ER3DV6	SN: 2328	14-Oct-16 (No. ER3-2328_Oct16)	Oct-17
DAE4	SN: 789	11-Nov-16 (No. DAE4-789_Nov16)	Nov-17
Secondary Standards	ID	Check Date (in house)	Scheduled Check
Power meter E4419B	SN: GB41293874	06-Apr-16 (in house check Jun-16)	In house check: Jun-18
Power sensor E4412A	SN: MY41498087	06-Apr-16 (in house check Jun-16)	In house check: Jun-18
Power sensor E4412A	SN: 000110210	06-Apr-16 (in house check Jun-16)	In house check: Jun-18
RF generator HP 8648C	SN: US3642U01700	04-Aug-99 (in house check Jun-16)	In house check: Jun-18
Network Analyzer HP 8753E	SN: US37390585	18-Oct-01 (in house check Ocl-16)	In house check: Oct-17
Calibrated by:	Name Johannes Kurikka	Function Laboratory Technician	Signature Min hun
Approved by:	Katja Pokovic	Technical Manager	ille the
			Issued: January 16, 2017

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Schwelzerischer Kalibrierdienst Service suisse d'étalonnage Servizio svizzero di taratura Swiss Calibration Service

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Accreditation No.: SCS 0108

Accredited by the Swiss Accreditation Service (SAS) The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

Glossary:

 NORMx,y,z
 sensitivity in free space

 DCP
 diode compression point

 CF
 crest factor (1/duty_cycle) of the RF signal

 A, B, C, D
 modulation dependent linearization parameters

 Polarization φ
 φ rotation around probe axis

 Polarization β
 9 rotation around an axis that is in the plane normal to probe axis (at measurement center), i.e., 9 = 0 is normal to probe axis

 Connector Angle
 information used in DASY system to align probe sensor X to the robot coordinate system

Calibration is Performed According to the Following Standards:

- a) IEEE Std 1309-2005, " IEEE Standard for calibration of electromagnetic field sensors and probes, excluding antennas, from 9 kHz to 40 GHz", December 2005
- b) CTIA Test Plan for Hearing Aid Compatibility, Rev 3.0, November 2013

Methods Applied and Interpretation of Parameters:

- NORMX, y, z: Assessed for E-field polarization 9 = 0 for XY sensors and 9 = 90 for Z sensor (f ≤ 900 MHz in TEM-cell; f > 1800 MHz: R22 waveguide).
- NORM(f)x,y,z = NORMx,y,z * frequency_response (see Frequency Response Chart).
- DCPx,y,z: DCP are numerical linearization parameters assessed based on the data of power sweep with CW signal (no uncertainty required). DCP does not depend on frequency nor media.
- PAR: PAR is the Peak to Average Ratio that is not calibrated but determined based on the signal characteristics
- Ax,y,z; Bx,y,z; Cx,y,z; Dx,y,z; VRx,y,z: A, B, C, D are numerical linearization parameters assessed based on the data of power sweep for specific modulation signal. The parameters do not depend on frequency nor media. VR is the maximum calibration range expressed in RMS voltage across the diode.
- Spherical isotropy (3D deviation from isotropy): in a locally homogeneous field realized using an open waveguide setup.
- Sensor Offset: The sensor offset corresponds to the offset of virtual measurement center from the probe tip (on probe axis). No tolerance required.
- Connector Angle: The angle is assessed using the information gained by determining the NORMx (no uncertainty required).

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Probe ER3DV6

SN:2353

Manufactured: Calibrated: March 8, 2005 January 16, 2017

Calibrated for DASY/EASY Systems (Note: non-compatible with DASY2 system!)

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ER3DV6 -- SN:2353

DASY/EASY - Parameters of Probe: ER3DV6 - SN:2353

Basic Calibration Parameters

	Sensor X	Sensor Y	Sensor Z	Unc (k=2)
Norm $(\mu V/(V/m)^2)$	1.49	1.68	1.78	± 10.1 %
DCP (mV) ⁸	99.3	98.2	100.1	

Modulation Calibration Parameters

UID	Communication System Name		A dB	B dB√μV	С	D dB	VR mV	Unc [⊨] (k=2)
0	ĊW	X	0.0	0.0	1.0	0.00	210.4	±3.8 %
		Y	0.0	0.0	1.0		207.1	
		Z	0.0	0.0	1.0		201.5	

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

^B Numerical linearization parameter: uncertainty not required.
^E Uncertainty is determined using the max. deviation from linear response applying rectangular distribution and is expressed for the square of the field value.

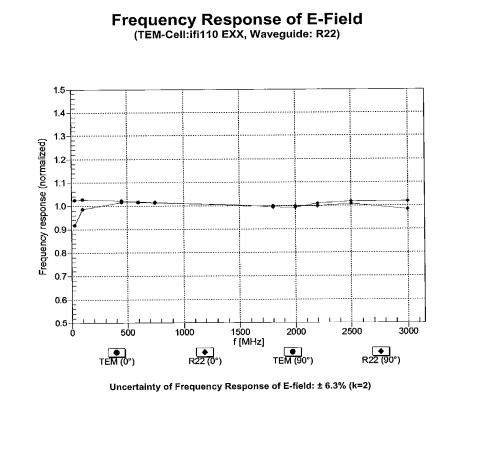
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ER3DV6 - SN:2353

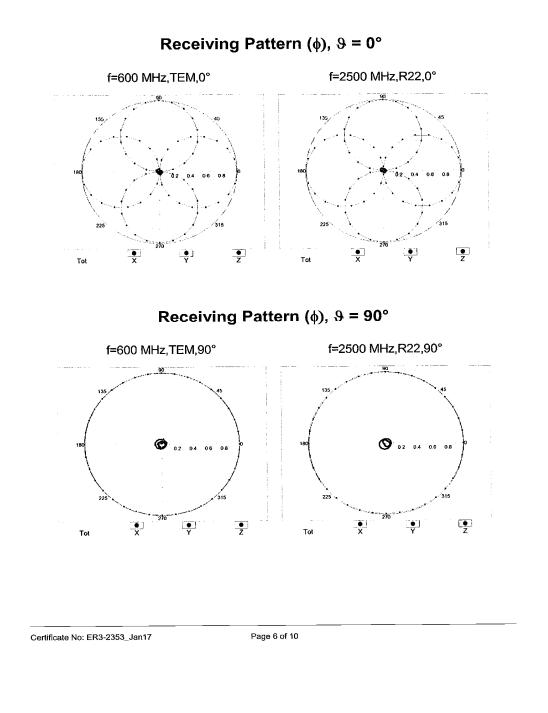
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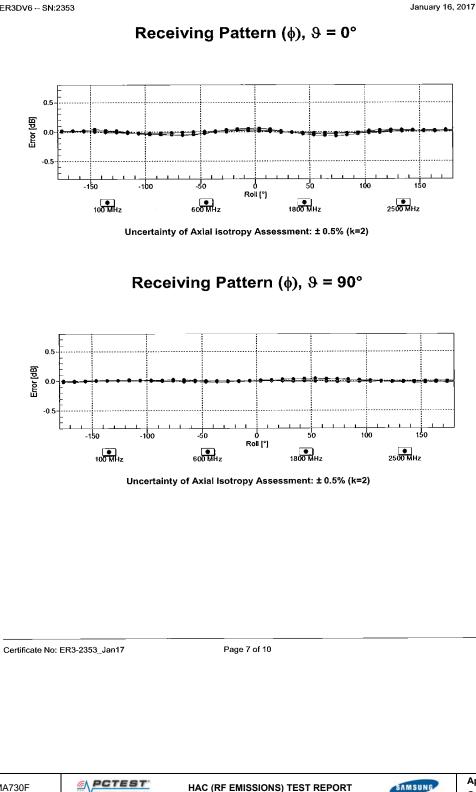
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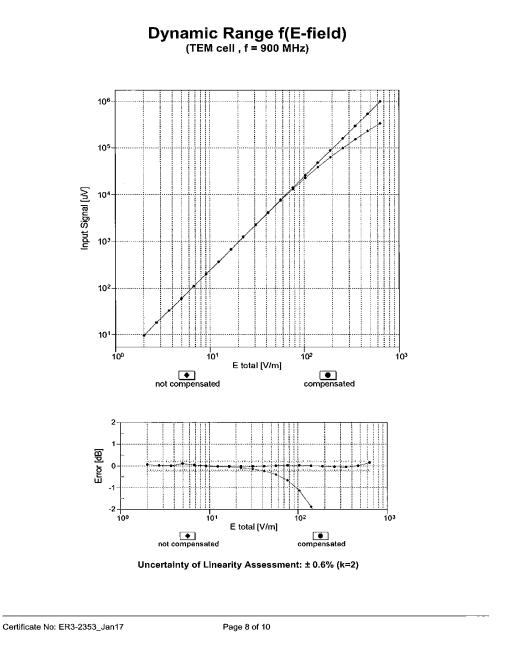
FCC ID: A3LSMA730F		HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
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ER3DV6 -- SN:2353

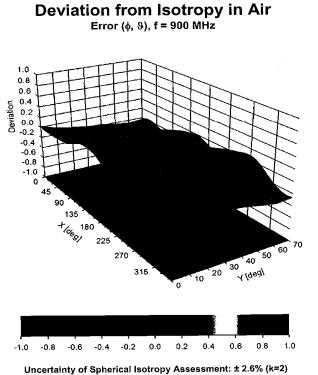


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ER3DV6 - SN:2353

DASY/EASY - Parameters of Probe: ER3DV6 - SN:2353

Other Probe Parameters

Sensor Arrangement	Rectangular
Connector Angle (°)	23.8
Mechanical Surface Detection Mode	enabled
Optical Surface Detection Mode	disabled
Probe Overall Length	337 mm
Probe Body Diameter	10 mm
Tip Length	10 mm
Tip Diameter	8 mm
Probe Tip to Sensor X Calibration Point	2.5 mm
Probe Tip to Sensor Y Calibration Point	2.5 mm
Probe Tip to Sensor Z Calibration Point	2.5 mm

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		Accreditation No.: SCS 0108
	Certificate	No: CD835V3-1082_May16
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Secondary Standards ID # Check Date (in house) Scheduled Check Power meter Agilent 4419B SN: GB42420191 09-Oct-09 (in house check Sep-14) In house check: Oct-17 Power sensor HP E4412A 05-Jan-10 (in house check Sep-14) SN: US38485102 In house check: Oct-17 09-Oct-09 (in house check Sep-14) Power sensor HP 8482A SN: US37295597 In house check: Oct-17 RF generator R&S SMT-06 SN: 832283/011 27-Aug-12 (in house check Oct-15) In house check: Oct-17 Network Analyzer HP 8753E SN: US37390585 18-Oct-01 (in house check Oct-15) In house check: Oct-16 Name

Function Signature Calibrated by: Jeton Kastrati Laboratory Technician Approved by: Katja Pokovic Technical Manager Issued: May 12, 2016 This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

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Zeughausstrasse 43, 8004 Zurich, Switzerland

Calibration Laboratory of

The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

References

[1] ANSI-C63.19-2011

Schmid & Partner

Engineering AG

American National Standard, Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

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Methods Applied and Interpretation of Parameters:

- Coordinate System: y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes. In coincidence with the standards [1], the measurement planes (probe sensor center) are selected to be at a distance of 15 mm above the top metal edge of the dipole arms.
- Measurement Conditions: Further details are available from the hardcopies at the end of the certificate. All
 figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector
 is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a
 directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- Antenna Positioning: The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- Feed Point Impedance and Return Loss: These parameters are measured using a HP 8753E Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any obstacles.
- E-field distribution: E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 15 mm (in z) above the metal top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, in the plane above the dipole surface.

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

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Measurement Conditions

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DASY system configuration, as far as not given	on page 1.	
DASY Version	DASY5	V52.8.8
Phantom	HAC Test Arch	
Distance Dipole Top - Probe Center	15 mm	
Scan resolution	dx, dy = 5 mm	
Frequency	835 MHz ± 1 MHz	
Input power drift	< 0.05 dB	

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Maximum Field values at 835 MHz

E-field 15 mm above dipole surface	condition	Interpolated maximum	
Maximum measured above high end	100 mW input power	107.5 V/m = 40.63 dBV/m	
Maximum measured above low end	100 mW input power	106.1 V/m = 40.51 dBV/m	
Averaged maximum above arm	100 mW input power	106.8 V/m ± 12.8 % (k=2)	

Appendix (Additional assessments outside the scope of SCS 0108)

Antenna Parameters

Frequency	Return Loss	Impedance	
800 MHz	16.4 dB	44.5 Ω - 13.4 jΩ	
835 MHz	26.3 dB	50.0 Ω + 4.9 jΩ	
900 MHz	16.4 dB	57.4 Ω - 14.7 jΩ	
950 MHz	21.9 dB	43.6 Ω + 4.0 jΩ	
960 MHz	17.2 dB	47.9 Ω + 13.5 jΩ	

3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

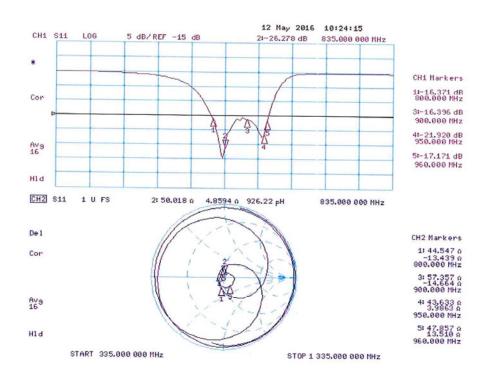
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Impedance Measurement Plot

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DASY5 E-field Result

Date: 10.05.2016

 (\Box)

Test Laboratory: SPEAG Lab2

DUT: HAC-Dipole 835 MHz; Type: CD835V3; Serial: CD835V3 - SN: 1082

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Communication System: UID 0 - CW ; Frequency: 835 MHz Medium parameters used: $\sigma = 0$ S/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³ Phantom section: RF Section Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY52 Configuration:

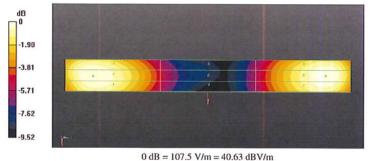
- Probe: ER3DV6 SN2336; ConvF(1, 1, 1); Calibrated: 31.12.2015; •
- Sensor-Surface: (Fix Surface) .
- Electronics: DAE4 Sn781; Calibrated: 04.09.2015
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.8.8(1258); SEMCAD X 14.6.10(7372)

Dipole E-Field measurement @ 835MHz/E-Scan - 835MHz d=15mm/Hearing Aid Compatibility Test (41x361x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 109.8 V/m; Power Drift = 0.02 dB Applied MIF = 0.00 dBRF audio interference level = 40.63 dBV/m

Emission category: M3

MIF scaled E-field

	Grid 3 M3 40.46 dBV/m
and the second	Grid 6 M4 35.62 dBV/m
	Grid 9 M3 40.37 dBV/m



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15. CONCLUSION

The measurements indicate that the wireless communications device complies with the HAC limits specified in accordance with the ANSI C63.19 Standard and FCC WT Docket No. 01-309 RM-8658. Precise laboratory measures were taken to assure repeatability of the tests. The tested device complies with the requirements in respect to all parameters specific to the test. The test results and statements relate only to the item(s) tested.

Please note that the M-rating for this equipment only represents the field interference possible against a hypothetical and typical hearing aid. The measurement system and techniques presented in this evaluation are proposed in the ANSI standard as a means of best approximating wireless device compatibility with a hearing-aid. The literature is under continual re-construction.

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